

24-Stage Frequency Divider

MC14521B

The MC14521B consists of a chain of 24 flip-flops with an input circuit that allows three modes of operation. The input will function as a crystal oscillator, an RC oscillator, or as an input buffer for an external oscillator. Each flip-flop divides the frequency of the previous flip-flop by two, consequently this part will count up to $2^{24} = 16,777,216$. The count advances on the negative going edge of the clock. The outputs of the last seven-stages are available for added flexibility.

Features

- All Stages are Resettable
- Reset Disables the RC Oscillator for Low Standby Power Drain
- RC and Crystal Oscillator Outputs Are Capable of Driving External Loads
- Test Mode to Reduce Test Time
- V_{DD}' and V_{SS}' Pins Brought Out on Crystal Oscillator Inverter to Allow the Connection of External Resistors for Low-Power Operation
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load over the Rated Temperature Range
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Parameter	Symbol	Value	Unit
DC Supply Voltage Range	V_{DD}	-0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	V_{in} , V_{out}	-0.5 to V_{DD} +0.5	V
Input or Output Current (DC or Transient) per Pin	I_{in} , I_{out}	± 10	mA
Power Dissipation, per Package (Note 1)	P_D	500	mW
Ambient Temperature Range	T_A	-55 to +125	°C
Storage Temperature Range	T_{stg}	-65 to +150	°C
Lead Temperature (8-Second Soldering)	T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. Operating the device outside its recommended conditions, but still within its maximum rated limits may not cause immediate damage. However, doing so can lead to reduced performance, unpredictable behavior, and potentially shorten the device's lifespan or reliability.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C From 65 °C To 125 °C

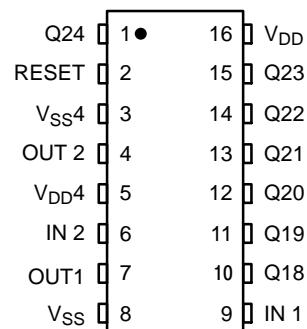
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



SOIC-16
D SUFFIX
CASE 751B

PIN ASSIGNMENT



MARKING DIAGRAMS



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Package

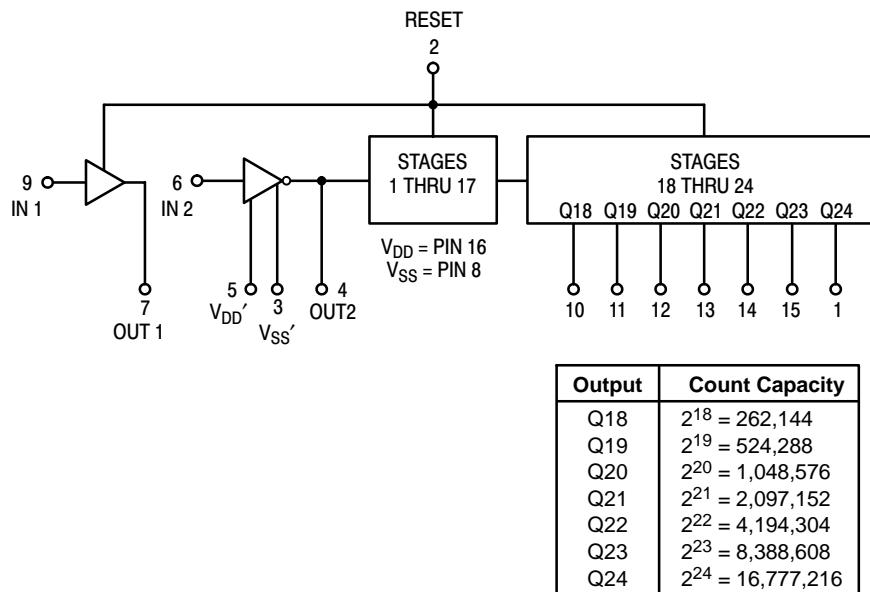
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been DISCONTINUED. Please refer to the table on page 2.

MC14521B

BLOCK DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
MC14521BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14521BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14521BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

DISCONTINUED (Note 2)

NLV14521BDG*	SOIC-16 (Pb-Free)	48 Units / Rail
--------------	----------------------	-----------------

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

* NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

2. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on [www.onsemi.com](#).

MC14521B

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V _{DD} Vdc	-55 °C		25 °C			125 °C		Unit	
			Min	Max	Min	Typ (Note 3)	Max	Min	Max		
Output Voltage V _{in} = V _{DD} or 0 "0" Level V _{in} = 0 or V _{DD}	V _{OL}	5.0	–	0.05	–	0	0.05	–	0.05	Vdc	
		10	–	0.05	–	0	0.05	–	0.05	Vdc	
		15	–	0.05	–	0	0.05	–	0.05	Vdc	
	V _{OH}	5.0	4.95	–	4.95	5.0	–	4.95	–	Vdc	
		10	9.95	–	9.95	10	–	9.95	–	Vdc	
		15	14.95	–	14.95	15	–	14.95	–	Vdc	
Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) "1" Level (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc)	V _{IL}	5.0	–	1.5	–	2.25	1.5	–	1.5	Vdc	
		10	–	3.0	–	4.50	3.0	–	3.0	Vdc	
		15	–	4.0	–	6.75	4.0	–	4.0	Vdc	
	V _{IH}	5.0	3.5	–	3.5	2.75	–	3.5	–	Vdc	
		10	7.0	–	7.0	5.50	–	7.0	–	Vdc	
		15	11	–	11	8.25	–	11	–	Vdc	
Output Drive Current (V _{OH} = 4.5 Vdc) (V _{OH} = 9.0 Vdc) (V _{OH} = 13 Vdc) (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc)	Source Pin 4	I _{OH}	5.0	-0.25	–	-0.2	-0.36	–	-0.14	–	mAdc
			10	-0.62	–	-0.5	-0.9	–	-0.35	–	mAdc
			15	-1.8	–	-1.5	-3.5	–	-1.1	–	mAdc
	Source Pins 1, 7, 10, 11, 12, 13, 14 and 15	I _{OH}	5.0	-3.0	–	-2.4	-4.2	–	-1.7	–	mAdc
			5.0	-0.64	–	-0.51	-0.88	–	-0.36	–	mAdc
	Sink	I _{OL}	10	-1.6	–	-1.3	-2.25	–	-0.9	–	mAdc
			15	-4.2	–	-3.4	-8.8	–	-2.4	–	mAdc
	Sink	I _{OL}	5.0	0.64	–	0.51	0.88	–	0.36	–	mAdc
		I _{OL}	10	1.6	–	1.3	2.25	–	0.9	–	mAdc
		I _{OL}	15	4.2	–	3.4	8.8	–	2.4	–	mAdc
Input Current	I _{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	μAdc	
Input Capacitance (V _{in} = 0)	C _{in}	–	–	–	–	5.0	7.5	–	–	pF	
Quiescent Current (Per Package)	I _{DD}	5.0	–	5.0	–	0.005	5.0	–	150	μAdc	
Total Supply Current (Note 4, 5) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching)	I _T	10	I _T = (0.42 μA/kHz) f + I _{DD}						μAdc		
		15	I _T = (0.85 μA/kHz) f + I _{DD}								
		5.0	I _T = (1.40 μA/kHz) f + I _{DD}								

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

4. The formulas given are for the typical characteristics only at 25 °C.

5. To calculate total supply current at loads other than 50 pF: I_T(C_L) = I_T(50 pF) + (C_L – 50) Vfk where: I_T is in μA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.003.

MC14521B

SWITCHING CHARACTERISTICS (Note 6) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ (Note 7)	Max	Unit
Output Rise and Fall Time (Counter Outputs) $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 12.5 \text{ ns}$	t_{TLH}, t_{THL}	5.0 10 15	— — —	100 50 40	200 100 80	ns
Propagation Delay Time Clock to Q18 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 4415 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 1667 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1275 \text{ ns}$ Clock to Q24 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 5915 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 2167 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1675 \text{ ns}$	t_{PHL}, t_{PLH}	5.0 10 15 5.0 10 15	— — — — — —	4.5 1.7 1.3 6.0 2.2 1.7	9.0 3.5 2.7 12 4.5 3.5	μs
Propagation Delay Time Reset to Q_n $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 1215 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 467 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 350 \text{ ns}$	t_{PHL}	5.0 10 15	— — —	1300 500 375	2600 1000 750	ns
Clock Pulse Width	$t_{WH(\text{cl})}$	5.0 10 15	385 150 120	140 55 40	— — —	ns
Clock Pulse Frequency	f_{cl}	5.0 10 15	— — —	3.5 9.0 12	2.0 5.0 6.5	MHz
Clock Rise and Fall Time	t_{TLH}, t_{THL}	5.0 10 15	— — —	— — —	15 5.0 4.0	μs
Reset Pulse Width	$t_{WH(\text{R})}$	5.0 10 15	1400 600 450	700 300 225	— — —	ns
Reset Removal Time	t_{rem}	5.0 10 15	30 0 -40	-200 -160 -110	— — —	ns

6. The formulas given are for the typical characteristics only at 25°C .

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

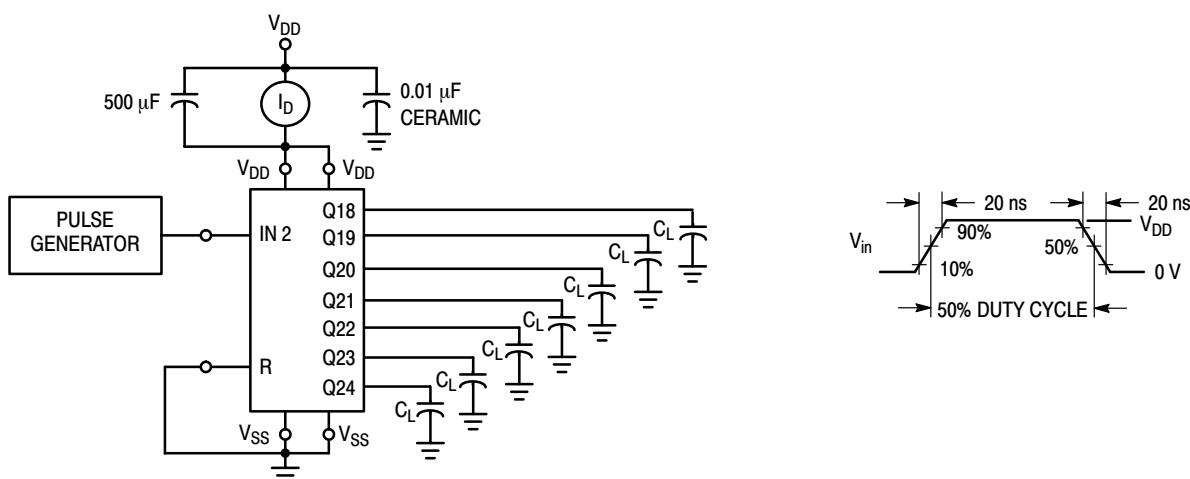


Figure 1. Power Dissipation Test Circuit and Waveform

MC14521B

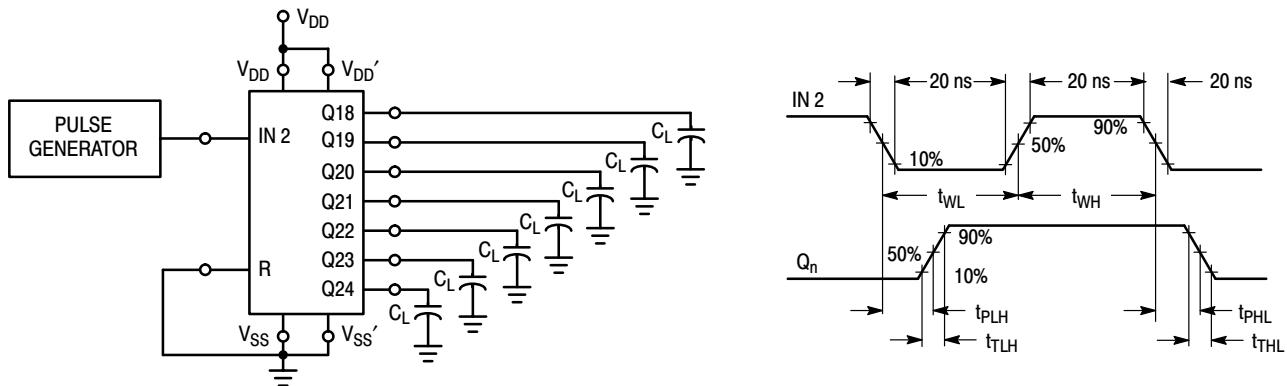
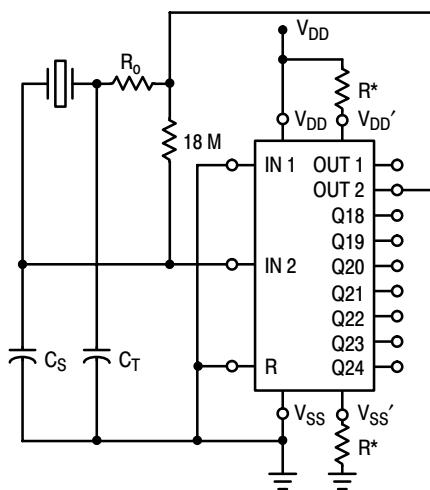


Figure 2. Switching Time Test Circuit and Waveforms



* Optional for low power operation,
 $10 \text{ k}\Omega \leq R \leq 70 \text{ k}\Omega$.

Figure 3. Crystal Oscillator Circuit

Characteristic	500 kHz Circuit	50 kHz Circuit	Unit
Crystal Characteristics Resonant Frequency Equivalent Resistance, R_S	500 1.0	50 6.2	kHz k Ω
External Resistor/Capacitor Values R_o C_T C_S	47 82 20	750 82 20	k Ω pF pF
Frequency Stability Frequency Change as a Function of V_{DD} ($T_A = 25^\circ\text{C}$) V_{DD} Change from 5.0 V to 10 V V_{DD} Change from 10 V to 15 V	+ 6.0 + 2.0	+ 2.0 + 2.0	ppm ppm
Frequency Change as a Function of Temperature ($V_{DD} = 10 \text{ V}$) T_A Change from -55°C to $+25^\circ\text{C}$ MC14521 only Complete Oscillator*	- 4.0 + 100	- 2.0 + 120	ppm ppm
T_A Change from $+25^\circ\text{C}$ to $+125^\circ\text{C}$ MC14521 only Complete Oscillator*	- 2.0 - 160	- 2.0 - 560	ppm ppm

*Complete oscillator includes crystal, capacitors, and resistors.

Figure 4. Typical Data for Crystal Oscillator Circuit

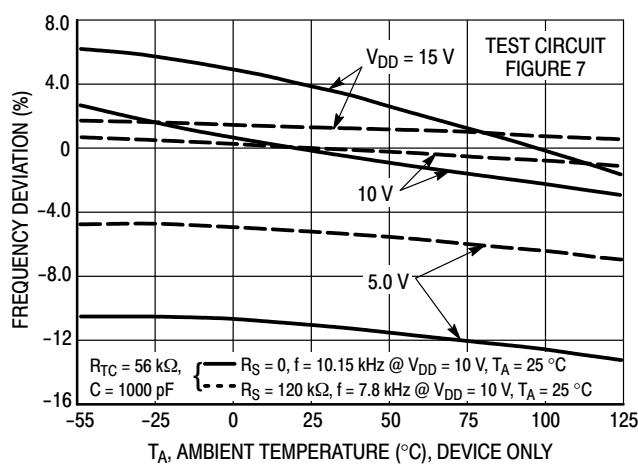


Figure 5. RC Oscillator Stability

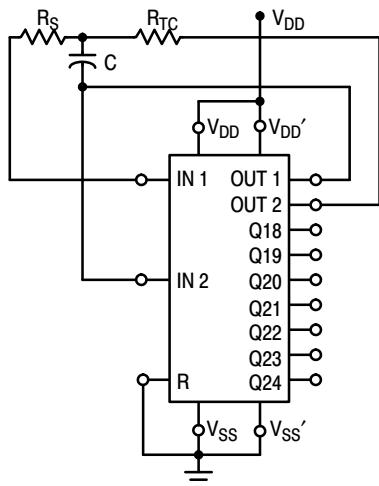


Figure 7. RC Oscillator Circuit

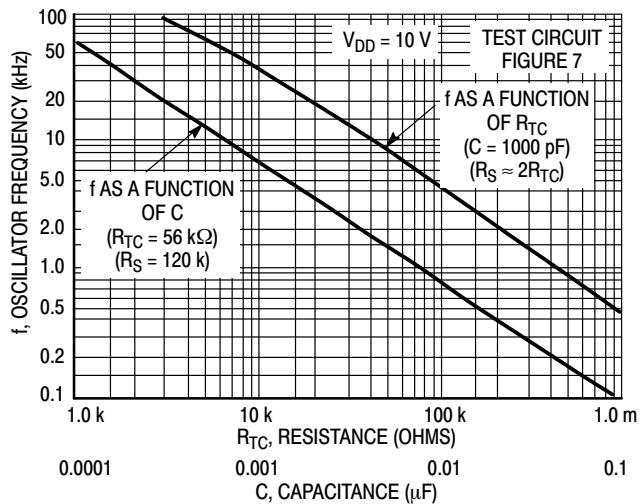


Figure 6. RC Oscillator Frequency as a Function of R_{TC} and C

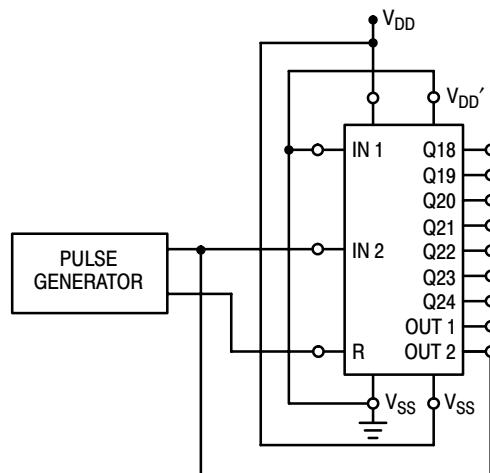


Figure 8. Functional Test Circuit

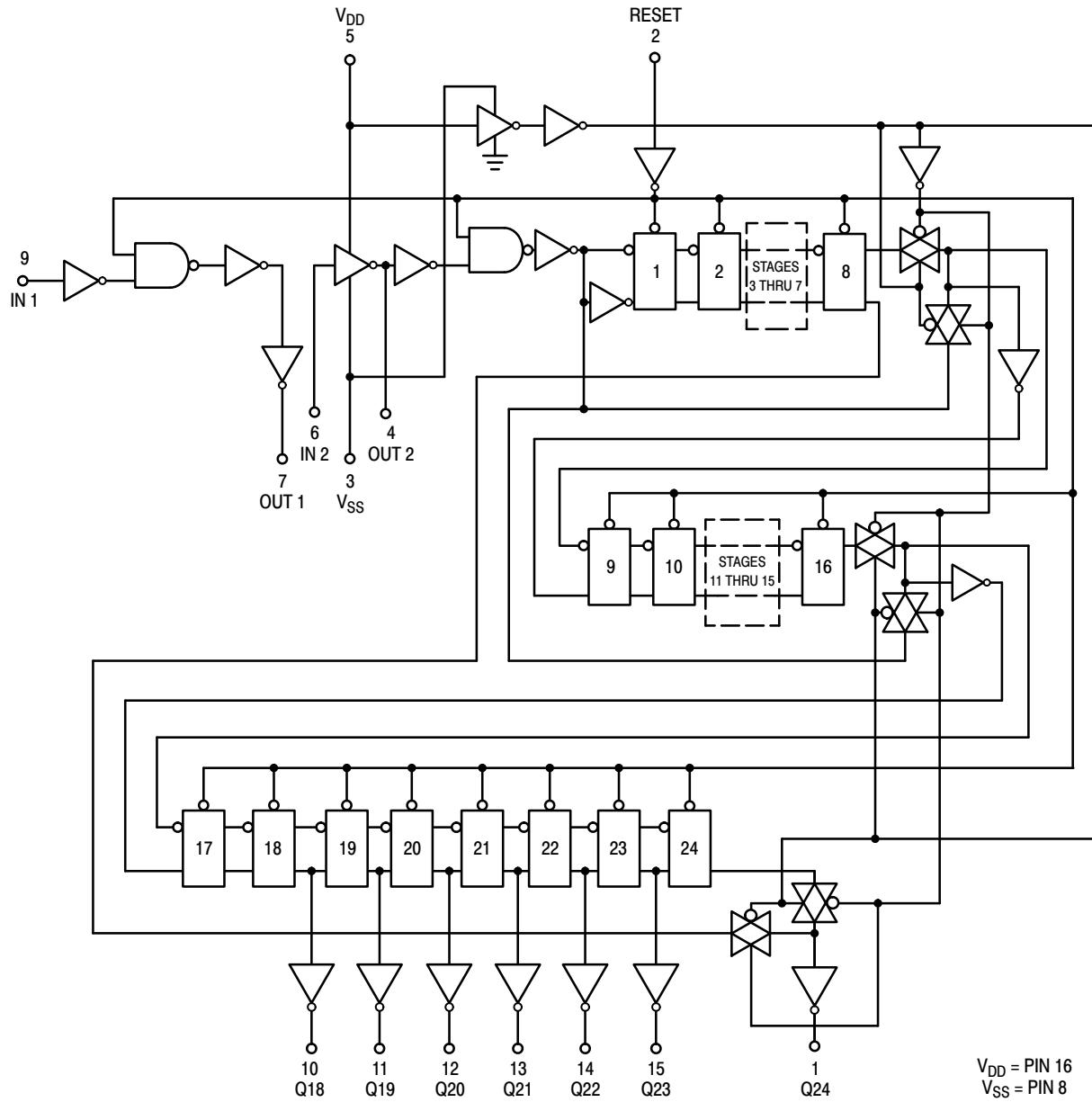
MC14521B

FUNCTIONAL TEST SEQUENCE

<p>A test function (see Figure 8) has been included for the reduction of test time required to exercise all 24 counter stages. This test function divides the counter into three 8-stage sections, and 255 counts are loaded in each of the 8-stage sections in parallel. All flip-flops are now at a logic "1". The counter is now returned to the normal 24-stages in series configuration. One more pulse is entered into Input 2 (In 2) which will cause the counter to ripple from an all "1" state to an all "0" state.</p>	Inputs		Outputs			Comments	
	Reset	In 2	Out 2	$V_{SS'}$	$V_{DD'}$	Q18 thru Q24	Counter is in three 8-stage sections in parallel mode Counter is reset. In 2 and Out 2 are connected together.
	1	0	0	V_{DD}	GND	0	First "0" to "1" transition on In 2, Out 2 node.
	0	1	1				255 "0" to "1" transitions are clocked into this In 2, Out 2 node.
	0	0					
	1	1					
	-	-					
	-	-					
	1	1					1 The 255th "0" to "1" transition.
	0	0					1
	0	0					1
	1	0					1 Counter converted back to 24-stages in series mode.
	1	0					1 Out 2 converts back to an output.
	0	1					0 Counter ripples from an all "1" state to an all "0" stage.

MC14521B

LOGIC DIAGRAM



REVISION HISTORY

Revision	Description of Changes	Date
11	Rebranded the Data Sheet to onsemi format. NLV14521BDG OPN marked as Discontinued.	10/3/2025

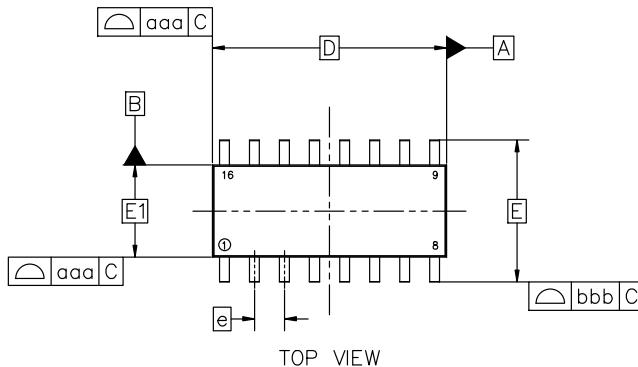
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.


SOIC-16 9.90x3.90x1.37 1.27P
CASE 751B
ISSUE M

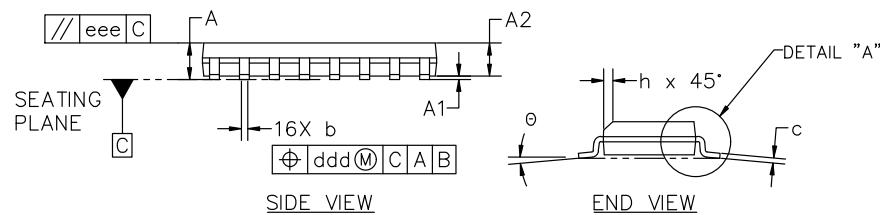
DATE 18 OCT 2024

NOTES:

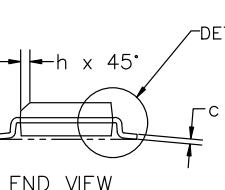
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



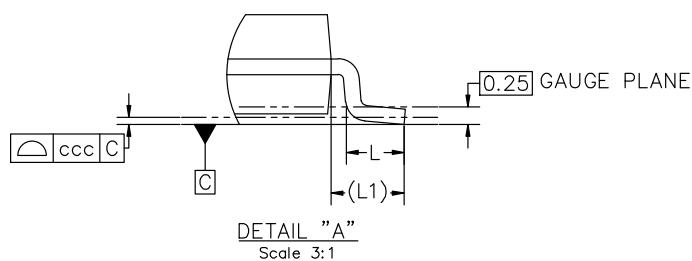
TOP VIEW



SIDE VIEW

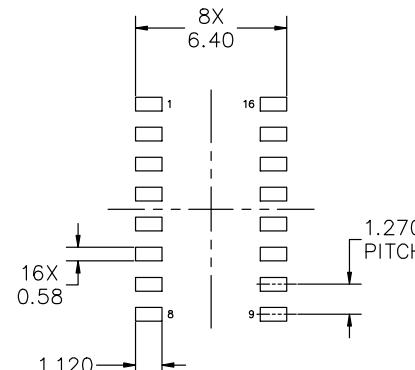


END VIEW

Detail "A"
Scale 3:1

MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.18	0.25
A2	1.25	1.37	1.50
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	---	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
θ	0°	---	7°

TOLERANCE OF FORM AND POSITION	
aaa	0.10
bbb	0.20
ccc	0.10
ddd	0.25
eee	0.10



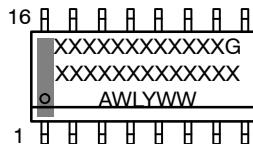
RECOMMENDED MOUNTING FOOTPRINT

*FOR ADDITIONAL INFORMATION ON OUR
PB-FREE STRATEGY AND SOLDERING DETAILS,
PLEASE DOWNLOAD THE onsemi SOLDERING
AND MOUNTING TECHNIQUES REFERENCE
MANUAL, SOLDERRM/D

DOCUMENT NUMBER:	98ASB42566B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-16 9.90x3.90x1.37 1.27P	PAGE 1 OF 2

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**GENERIC
MARKING DIAGRAM***



XXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot

Y = Year

WW = Work Week

G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
 PIN 1. COLLECTOR
 2. BASE
 3. Emitter
 4. NO CONNECTION
 5. Emitter
 6. BASE
 7. COLLECTOR
 8. COLLECTOR
 9. BASE
 10. Emitter
 11. NO CONNECTION
 12. Emitter
 13. BASE
 14. COLLECTOR
 15. Emitter
 16. COLLECTOR

STYLE 2:
 PIN 1. CATHODE
 2. ANODE
 3. NO CONNECTION
 4. CATHODE
 5. CATHODE
 6. NO CONNECTION
 7. ANODE
 8. CATHODE
 9. CATHODE
 10. ANODE
 11. NO CONNECTION
 12. CATHODE
 13. CATHODE
 14. NO CONNECTION
 15. ANODE
 16. CATHODE

STYLE 3:
 PIN 1. COLLECTOR, DYE #1
 2. BASE, #1
 3. Emitter, #1
 4. COLLECTOR, #1
 5. COLLECTOR, #2
 6. BASE, #2
 7. Emitter, #2
 8. COLLECTOR, #2
 9. COLLECTOR, #3
 10. BASE, #3
 11. Emitter, #3
 12. COLLECTOR, #3
 13. COLLECTOR, #4
 14. BASE, #4
 15. Emitter, #4
 16. COLLECTOR, #4

STYLE 4:
 PIN 1. COLLECTOR, DYE #1
 2. COLLECTOR, #1
 3. COLLECTOR, #2
 4. COLLECTOR, #2
 5. COLLECTOR, #3
 6. COLLECTOR, #3
 7. COLLECTOR, #4
 8. COLLECTOR, #4
 9. BASE, #4
 10. Emitter, #4
 11. BASE, #3
 12. Emitter, #3
 13. BASE, #2
 14. Emitter, #2
 15. BASE, #1
 16. Emitter, #1

STYLE 5:
 PIN 1. DRAIN, DYE #1
 2. DRAIN, #1
 3. DRAIN, #2
 4. DRAIN, #2
 5. DRAIN, #3
 6. DRAIN, #3
 7. DRAIN, #4
 8. DRAIN, #4
 9. GATE, #4
 10. SOURCE, #4
 11. GATE, #3
 12. SOURCE, #3
 13. GATE, #2
 14. SOURCE, #2
 15. GATE, #1
 16. SOURCE, #1

STYLE 6:
 PIN 1. CATHODE
 2. CATHODE
 3. CATHODE
 4. CATHODE
 5. CATHODE
 6. CATHODE
 7. CATHODE
 8. CATHODE
 9. ANODE
 10. ANODE
 11. ANODE
 12. ANODE
 13. ANODE
 14. ANODE
 15. ANODE
 16. ANODE

STYLE 7:
 PIN 1. SOURCE N-CH
 2. COMMON DRAIN (OUTPUT)
 3. COMMON DRAIN (OUTPUT)
 4. GATE P-CH
 5. COMMON DRAIN (OUTPUT)
 6. COMMON DRAIN (OUTPUT)
 7. COMMON DRAIN (OUTPUT)
 8. SOURCE P-CH
 9. SOURCE P-CH
 10. COMMON DRAIN (OUTPUT)
 11. COMMON DRAIN (OUTPUT)
 12. COMMON DRAIN (OUTPUT)
 13. GATE N-CH
 14. COMMON DRAIN (OUTPUT)
 15. COMMON DRAIN (OUTPUT)
 16. SOURCE N-CH

DOCUMENT NUMBER:	98ASB42566B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-16 9.90x3.90X1.37 1.27P	PAGE 2 OF 2

onsemi and **Onsemi** are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

onsemi, **ONSEMI**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales

